## **BF959**

# **VHF Transistor**

### **NPN Silicon**

### **Features**

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
Collector - Emitter Voltage	V <sub>CEO</sub>	20	Vdc	
Collector - Base Voltage	V <sub>CBO</sub>	30	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	Vdc	
Collector Current – Continuous	Ic	100	mAdc	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

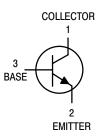
\*For additional information on our Pb-Free strategy and soldering details, please

download the ON Semiconductor Soldering and Mounting Techniques

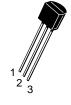


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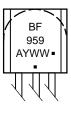
http://onsemi.com



### MARKING DIAGRAM



TO-92 CASE 29 STYLE 21



BF959 = Device Code A = Assembly Location

Y = Year
WW = Work Week
= Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BF959	TO-92	5000 Units/Box
BF959G	TO-92 (Pb-Free)	5000 Units/Box
BF959RL1	TO-92	2000/Tape & Reel
BF959RL1G	TO-92 (Pb-Free)	2000/Tape & Reel
BF959ZL1	TO-92	2000/Ammo Pack
BF959ZL1G	TO-92 (Pb-Free)	2000/Ammo Pack

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

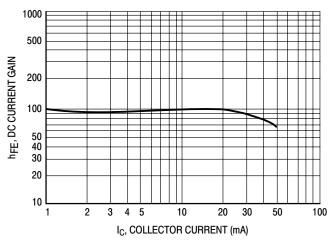
Reference Manual, SOLDERRM/D.

1

### **BF959**

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

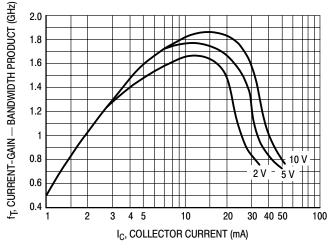
Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	20	-	-	Vdc	
Collector – Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	30	-	_	Vdc	
Emitter – Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	3.0	-	_	Vdc	
Collector Cutoff Current (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0)	Ісво	-	-	100	nAdc	
ON CHARACTERISTICS						
DC Current Gain ( $I_C = 5.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 20 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ )	h <sub>FE</sub>	35 40		- -	_	
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 30 mAdc, I <sub>B</sub> = 2.0 mAdc)	V <sub>CE(sat)</sub>	-	-	1.0	Vdc	
Base – Emitter Saturation Voltage (I <sub>C</sub> = 30 mAdc, I <sub>B</sub> = 2.0 mAdc)	V <sub>BE(sat)</sub>	-	-	1.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS						
$\begin{aligned} & \text{Current-Gain - Bandwidth Product} \\ & \text{(I}_{\text{C}} = 20 \text{ mAdc, V}_{\text{CE}} = 10 \text{ Vdc, f} = 100 \text{ MHz)} \\ & \text{(I}_{\text{C}} = 30 \text{ mAdc, V}_{\text{CE}} = 10 \text{ Vdc, f} = 100 \text{ MHz)} \end{aligned}$	f <sub>T</sub>	700 600	_ _	_ _	MHz	
Common Emitter Feedback Capacitance (V <sub>CB</sub> = 10 Vdc, P <sub>f</sub> = 0, f = 10 MHz)	C <sub>re</sub>	-	0.65	_	pF	
Noise Figure (I <sub>C</sub> = 4.0 mA, $V_{CE}$ = 10 V, $R_{S}$ = 50 $\Omega$ , f = 200 MHz)	N <sub>f</sub>	_	3.0	-	dB	



200
200
100
200
100
20
101
2 3 4 5 10 20 30 50
I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 1. h<sub>FE</sub> at 10 V

Figure 2.  $V_{CE(sat)}$  at  $I_C/I_B = 10$ 



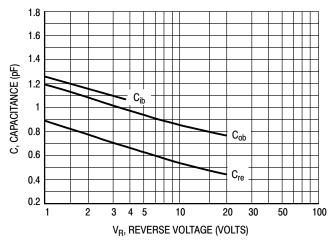
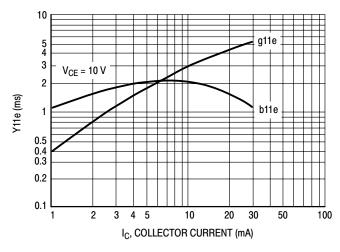


Figure 3. Current-Gain - Bandwidth Product

Figure 4. Capacitances



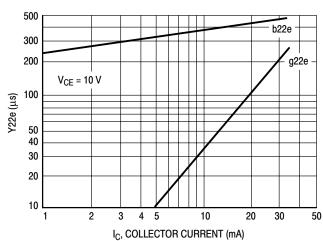


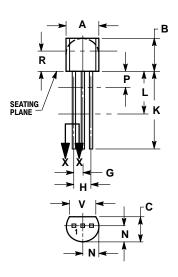
Figure 5. Input Impedance at 30 MHz

Figure 6. Output Impedance at 30 MHz

### **BF959**

### PACKAGE DIMENSIONS

**TO-92 TO-226AA**CASE 29-11
ISSUE AL





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
   V14 FM 1082
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
   IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

### STYLE 21:

PIN 1. COLLECTOR 2. EMITTER 3. BASE

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